



#### SOT223 N-CHANNEL ENHANCEMENT MODE VERTICAL DMOS FET

### **Features and Benefits**

- 6A Pulse Drain Current
- Fast Switching Speed
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

## Applications

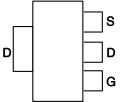
- DC-DC Converters
- Solenoids / Relay Driver for Automotive

### **Mechanical Data**

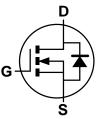
- Case: SOT223
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish (3)
- Weight: 0.112 grams (Approximate)



Top View



Pin Out - Top



Equivalent Circuit

### Ordering Information (Note 4)

Part Number	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZVN2110GTA	ZVN2110	7	8	1,000

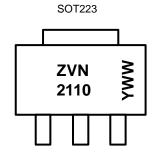
Notes: 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.

2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

## **Marking Information**



ZVN2110 = Product Type Marking Code YWW = Date Code Marking Y or  $\overline{Y}$  = Last Digit of Year (ex: 5= 2015) WW or  $\overline{W}W$  = Week Code (01~53)



# **ABSOLUTE MAXIMUM RATINGS** (@T<sub>A</sub> = +25°C, unless otherwise stated.)

Characteristic	Symbol	Value	Unit
Drain-Source Voltage	V <sub>DSS</sub>	100	V
Gate-Source Voltage	V <sub>GSS</sub>	±20	V
Continuous Drain Current	ID	500	mA
Pulsed Drain Current	I <sub>DM</sub>	6	A
Power Dissipation	PD	2	W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

# **ELECTRICAL CHARACTERISTICS** (@T<sub>A</sub> = +25°C, unless otherwise stated.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltage	<b>BV</b> <sub>DSS</sub>	100	-	-	V	$V_{GS} = 0V, I_D = 1mA$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	-	-	1 100	μΑ μΑ	V <sub>DS</sub> = 100V, V <sub>GS</sub> = 0V V <sub>DS</sub> = 80V, V <sub>GS</sub> = 0V, T= +125°C(6)	
Gate-Body Leakage	IGSS	-	0.1	20	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
On-State Drain Current (Note 5)	I <sub>D(ON)</sub>	1.5	2	-	Α	V <sub>GS</sub> = 10V, V <sub>DS</sub> = 25V	
ON CHARACTERISTICS							
Gate-Source Threshold Voltage	V <sub>GS(TH)</sub>	0.8	-	2.4	V	$V_{DS} = V_{GS}, I_D = 1mA$	
Static Drain-Source On-State Resistance (Note 5)	R <sub>DS(ON)</sub>	-	-	4	Ω	V <sub>GS</sub> = 10V, I <sub>D</sub> =1A	
Forward Transconductance (Notes 5 & 6)	<b>g</b> fs	250	350	-	mS	V <sub>DS</sub> = 25V, I <sub>D</sub> = 1A	
DYNAMIC CHARACTERISTICS						·	
Input Capacitance (Note 6)	Ciss	-	59	75	pF	V <sub>DS</sub> = 25V, V <sub>GS</sub> = 0V, f = 1.0MHz	
Common Source Output Capacitance (Note 6)	C <sub>oss</sub>	-	16	25	pF		
Reverse Transfer Capacitance (Note 6)	Crss	-	4	8	pF		
Turn-On Delay Time (Notes 6 & 7)	t <sub>D(ON)</sub>	-	4	7	ns	V <sub>DD</sub> = 25V, I <sub>D</sub> = 1A	
Rise Time (Notes 6 & 7)	t <sub>R</sub>	-	4	8	ns		
Turn-Off Delay Time (Notes 6 & 7)	t <sub>D(OFF)</sub>	-	8	13	ns		
Fall Time (Notes 6 & 7)	t <sub>F</sub>	-	8	13	ns	]	

# DRAIN-SOURCE DIODE CHARACTERISTICS

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Diode Forward Voltage (Note 5)	Vsd	-	0.82	-	V	Is=0.32A, Vgs=0
Reverse Recovery Time	Trr	-	112	-	ns	IF=0.32A, Vgs=0, IR=0.1A

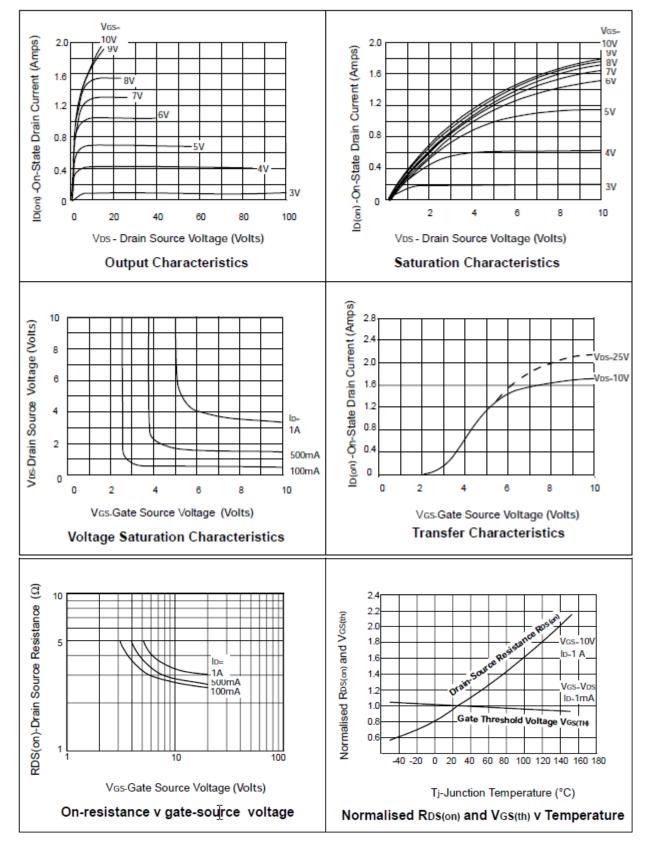
5. Measured under pulsed conditions. Width=300 $\mu$ s. Duty cycle  $\leq$ 2%.

6. Sample test.

Notes:

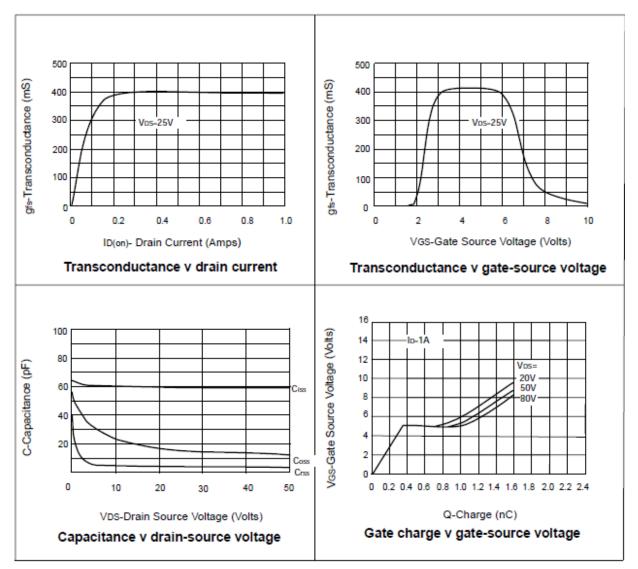
7. Switching times measured with  $50\Omega$  source impedance and <5ns rise time on a pulse generator.





# TYPICAL CHARACTERISTICS



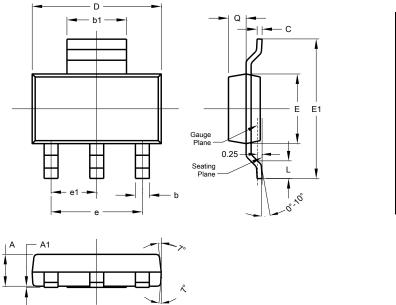


# **TYPICAL CHARACTERISTICS**



# **Package Outline Dimensions**

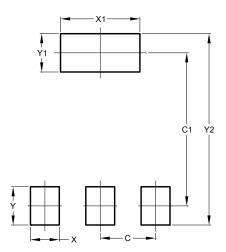
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



SOT223					
Dim	Min	Max	Тур		
Α	1.55	1.65	1.60		
A1	0.010	0.15	0.05		
b	0.60	0.80	0.70		
b1	2.90	3.10	3.00		
С	0.20	0.30	0.25		
D	6.45	6.55	6.50		
E	3.45	3.55	3.50		
E1	6.90	7.10	7.00		
е	-	-	4.60		
e1	-	-	2.30		
L	0.85	1.05	0.95		
Q	0.84	0.94	0.89		
All Dimensions in mm					

### **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
C	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00



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